

# AIT

Advanced Instrument Technology



## Resistivity & Sheet Resistance Measuring System

Model **CMT-SR2000N**

### Specifications



Advanced Instrument Technology  
[www.mdc-europe.com](http://www.mdc-europe.com)

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### 1. Introduction

The CMT-SR2000N is a full automatic system to measure and map Sheet Resistance and Resistivity of Silicon wafer.

This system can be operated by itself and furthermore, perfect remote control is available using a PC and exclusive software, and it gives various data analyses.

## 2. Features

- X-Y-Z axis full automatic system.
- Auto & Manual range selection.
- Systems for 8" wafer.
- Perfect remote control by operating software.
- Data analysis. (2D, 3D map, Data map, etc)
- ASTM & SEMI quick measurement mode.

## 3. Configuration

The system consists of following components.

- 4point probe head unit.
- Z-axis Robot arm.
- Revolution sample stage chuck. (X-Y Axis)
- Membrane keyboard panel.
- LCD display window.
- Remote control communication port.
- Vacuum hose connector. (200mmHg)
- Software (Windows™.)
- Standard accessories
  - Power connection cable.
  - Remote control communication cable.
  - Operating & service guide.

## 4. Specifications

- Sheet resistance measurement
  - Measuring method : Contacted by 4-point probe
  - Measuring range : 1 mohm/sq ~ 2 Mohm/sq
- Resistivity measurement
  - Measuring method : Contacted by 4-point probe (Input thickness)
  - Measuring range : 10.0  $\mu$ ohm·cm ~ 200.0 Kohm·cm
- Current Source
  - 10nA to 100mA
  - DVM 0V to 2,000mV
  - Accuracy: 0.2 % (KRISS Circuits)
- Measurement Accuracy
  - $\pm$  0.5 % (VLSI Standard Wafer, When 23°C)
- 4-point probe (JANDEL ENG.)
  - Pin spacing : 25 ~ 50 mils by 5mil increments.
  - Pin Load : 10 ~ 250 gram/pin
  - Pin radius : 12.5~500 microns (polished 2 $\mu$  diamond)
  - Tolerance :  $\pm$  0.01 mm
  - Needles : Solid tungsten carbide  $\phi$  0.40 mm
- Operating software
  - Measurement condition creation. : Wafer type, measure point interval, etc.
  - Save & load : data, wafer type, measure point, etc.
  - Data analysis : 2D, 3D mapping, Data map, etc.
  - On/Off : Remote, Vacuum.
  - Data & mapping printout.
- Measurement mode (S/W)
  - Auto measurement : Point interval designation by user.
  - Quick measurement : ASTM & SEMI Mode.
  - Point measurement : Appointment on wafer by mouse.
  - Manual measurement : Appointment on wafer by arrow key.

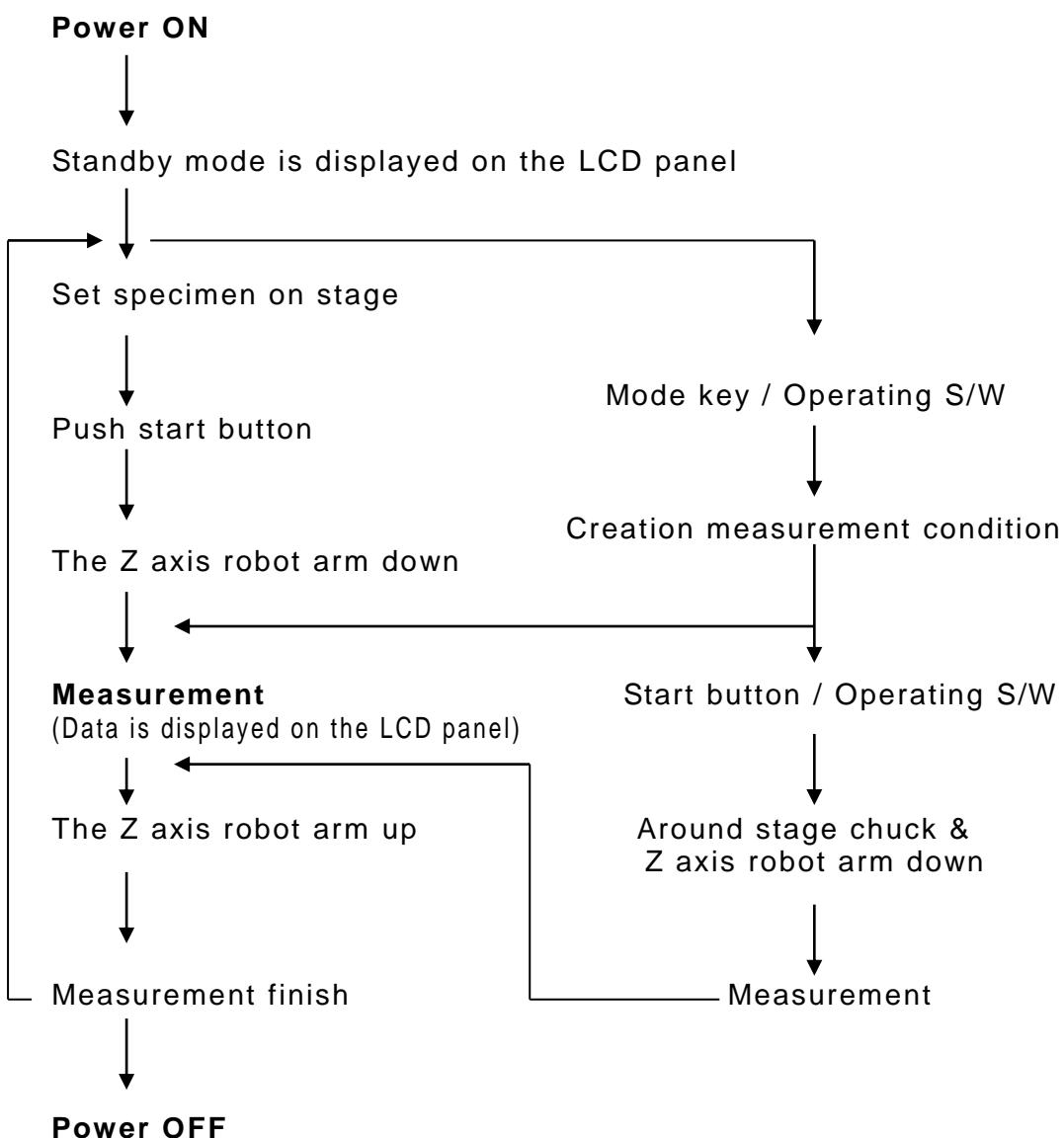
## 5. Specimen

- Wafer : up to 8" (Size) & 6mm (Thickness)

## 6. Measuring time

- Approx. 3 ± 1 sec/point

## 7. Measuring flow



## 8. Software [Windows ™]

- Operating personal computer :  
IBM PC/AT compatible PENTIUM ~
- Connect com port(RS232C) of PC and operating com port of CMT-SR2000N.

## 9. Utility Requirements

- Power requirements (1 Line)
  - Line voltage : AC 220V ± 10%
  - Electric power : 55 W, 250 mA
  - Line frequency : 50 ~ 60 Hz
- Stage Chuck Vacuum requirements (1 Line)
  - Vacuum : About 200mmHg (1 Line)
  - Vacuum Hose : Urethane 4mm

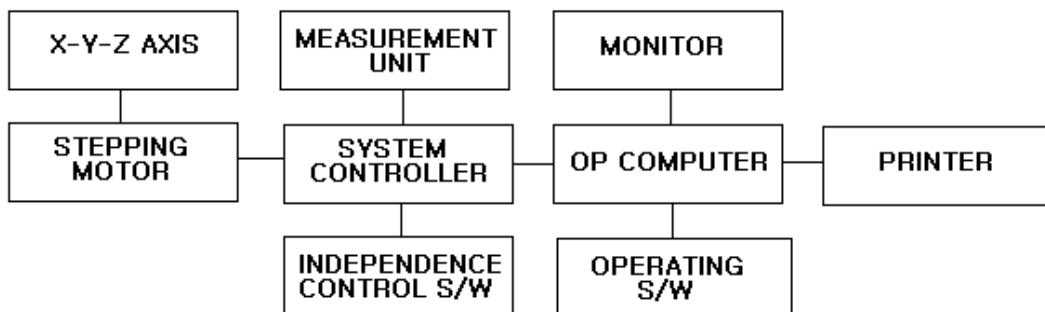
## 10. Weight and Dimension

- Net Weight : 13.4 KG
- Dimension
  - Net : 562mm(W)×254mm(L)×250mm(H)
  - Carton Packed : 710mm(W)×410mm(L)×400mm(H)

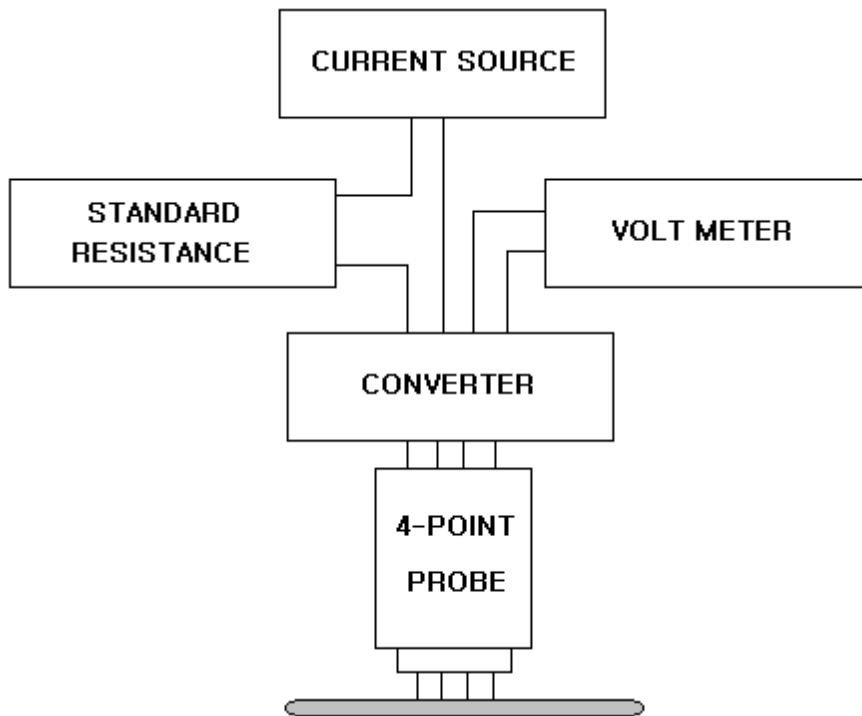
## 11. Operating Environment

- Temperature range : 23° ± 1°C
- Relative humidity : 30 ~ 70 %
- Avoid placing the system near a source of RFI, vibration and sources of gas.
- Avoid large changes in temperature.

## 12. System Construction Map

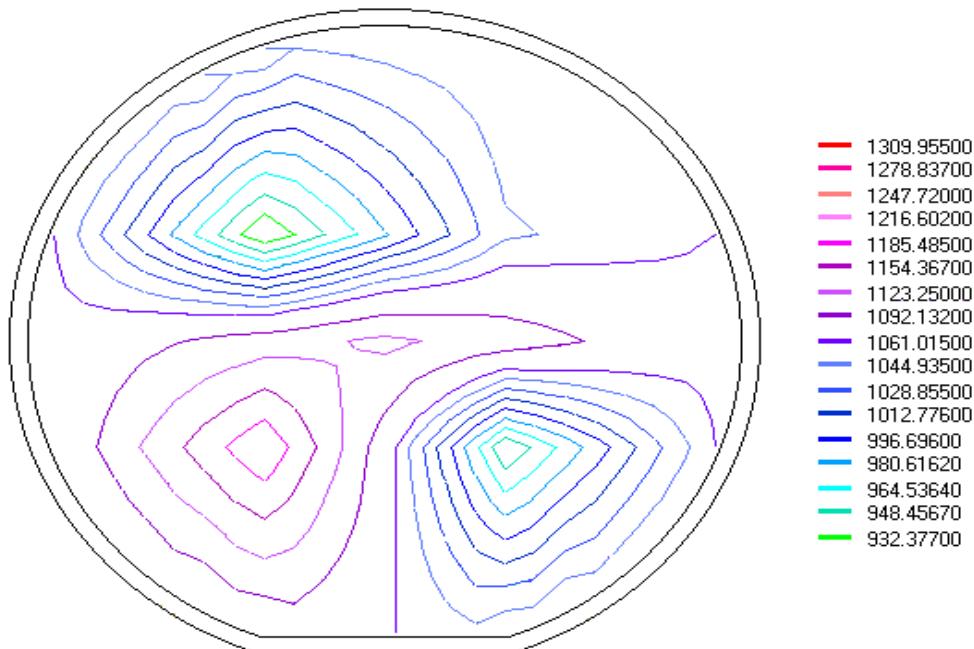


## 13. Measurement Construction Map



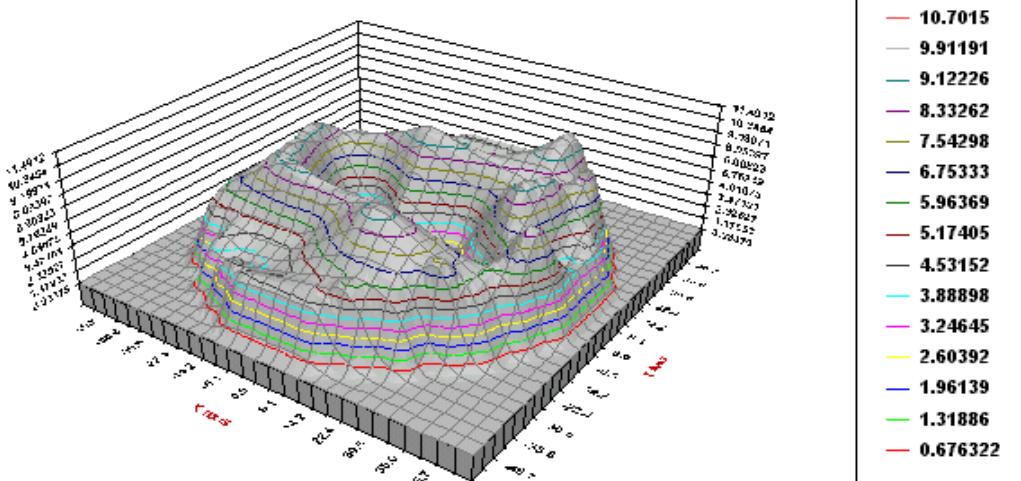
## 14. Mapping Sample

### Contour Map Analysis [ ohm / sq ]



1. Sample ID : test000001
2. Sample Type : samtype001 [ Size (mm) - Sample: 203.2, Flat: 6, Exclusion: 5 ]
3. Measure Mode : None
4. Thickness : 0.01
5. Date/Time : 1998-09-16 10:04:26

### 3D Map Analysis [ ohm ]



1. Sample ID : test000006
  2. Sample Type : lnone [ Size (mm) - X: 101.6, Y: 4, Exclusion: 4 ]
  3. Measure Mode : None
  4. Thickness : 0.0
  5. Date/Time : 1998년 11월 16일 월요일 오후 7:38:04
  6. Op.ID : sj5
  7. Analysis [ ohm ]
- |                    |                   |                       |
|--------------------|-------------------|-----------------------|
| 1) Max : 11.49119  | 2) Min : 0.03379  | 3) Ave : 5.17405      |
| 4) StDev : 0.66030 | 5) Uni : 99.41362 | 6) Max-Min : 11.45740 |